

isc Silicon NPN Power Transistors

TIP41C

DESCRIPTION

- DC Current Gain -h_{FE} = 30(Min)@ I_C= 0.3A
- · Collector-Emitter Sustaining Voltage-
 - : V_{CEO(SUS)} = 100V(Min)
- Complement to Type TIP42C
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

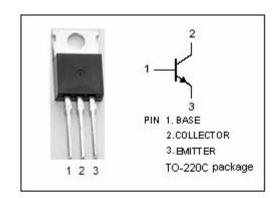
Designed for use in general purpose amplifer and switching applications

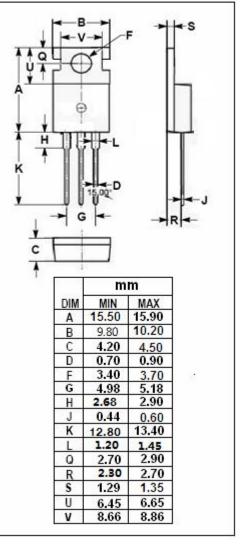
ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{СВО}	Collector-Base Voltage	100	V	
V _{CEO}	Collector-Emitter Voltage	100	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current-Continuous	6	Α	
I _{CM}	Collector Current-Peak	10	Α	
I _B	Base Current	3	Α	
Pc	Collector Power Dissipation T _C =25°C	65	W	
	Collector Power Dissipation T _a =25°C	2		
T _j	Junction Temperature	erature 150		
T _{stg}	Storage Temperature Range -65~150		$^{\circ}$	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	1.92	°C/W
R _{th j-a}	j-a Thermal Resistance,Junction to Ambient		°C/W





isc website: <u>www.iscsemi.com</u>

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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT			
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 30mA; I _B = 0	100		V			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 6A; I _B = 1.5A		1.5	V			
V _{BE(on)}	Base-Emitter On Voltage	I _C = 6A; V _{CE} = 4V		2.0	V			
І _{СВО}	Collector Cutoff Current	V _{CB} = 100V; I _E = 0		0.4	mA			
Iceo	Collector Cutoff Current	V _{CE} = 60V; I _B = 0		0.7	mA			
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0		1.0	mA			
h _{FE-1}	DC Current Gain	Ic= 0.3A; Vc== 4V	30					
h _{FE-2}	DC Current Gain	I _C = 3A; V _{CE} = 4V	15					
f⊤	Current-Gain—Bandwidth Product	I _C = 0.5A ; V _{CE} = 10V	3		MHz			
Switching Time								
ton	Turn-On Time	I_{C} = 6A; I_{B1} = - I_{B2} = 0.6A; $V_{BE(off)}$ = 4V, R_{L} = 5 Ω		0.6	μs			
t _{off}	Turn-Off Time			1.0	μ s			

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